

Supporting information

A Novel Compositional-Gradient Hierarchical ZnS/GeS₂ Heterojunction Nanorods for High-Rate and Durable Sodium Storage

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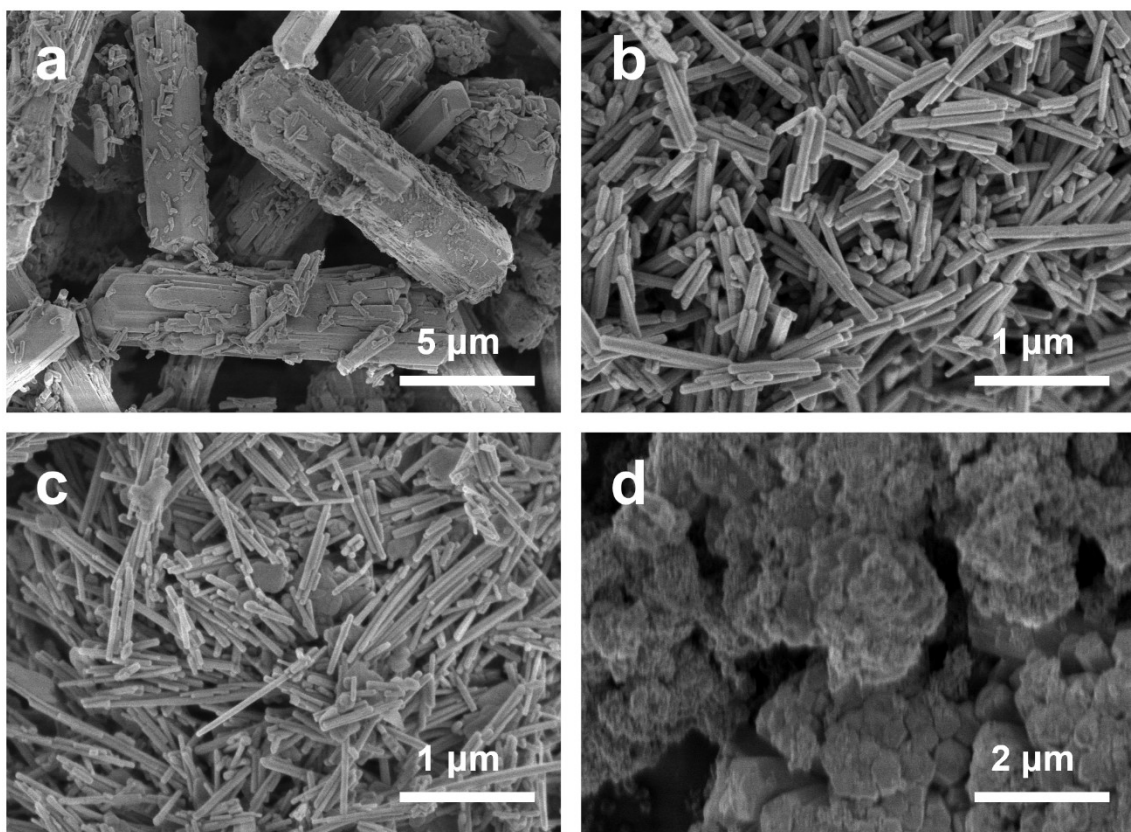


Fig. S1. (a) SEM image of the precursor obtained at pH 8, (b) Precursor prepared at pH 9, (c) Sample synthesized at pH 10, (d) Sample prepared with excessive NH_3 .

At low pH, no solid precursor forms; when the pH is moderately increased by adding a small amount of $\text{NH}_3 \cdot \text{H}_2\text{O}$, uniform nanorods are obtained, whereas excessively high pH disrupts the growth process and leads to fragmented and unstable rod structures.

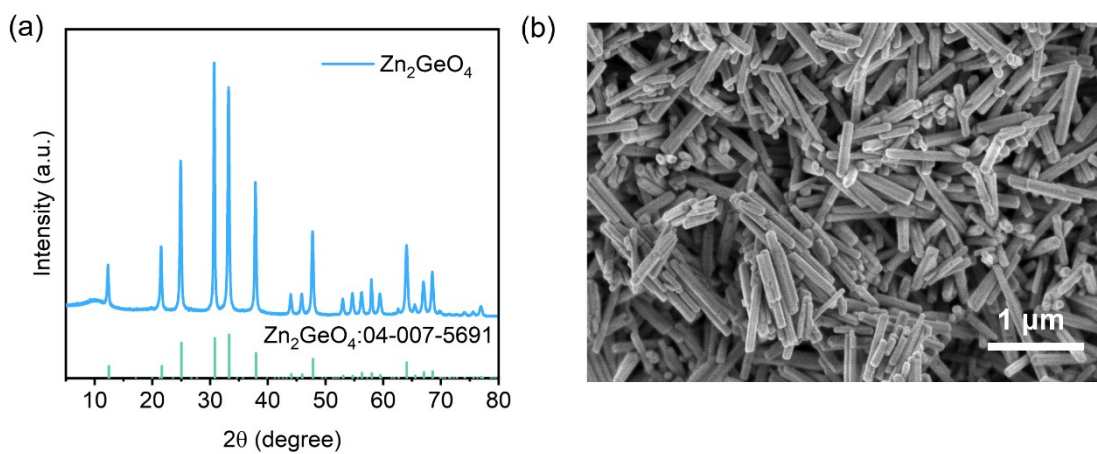


Fig. S2. Physical characterizations of Zn_2GeO_4 precursor. (a) XRD patterns and (b) SEM image.

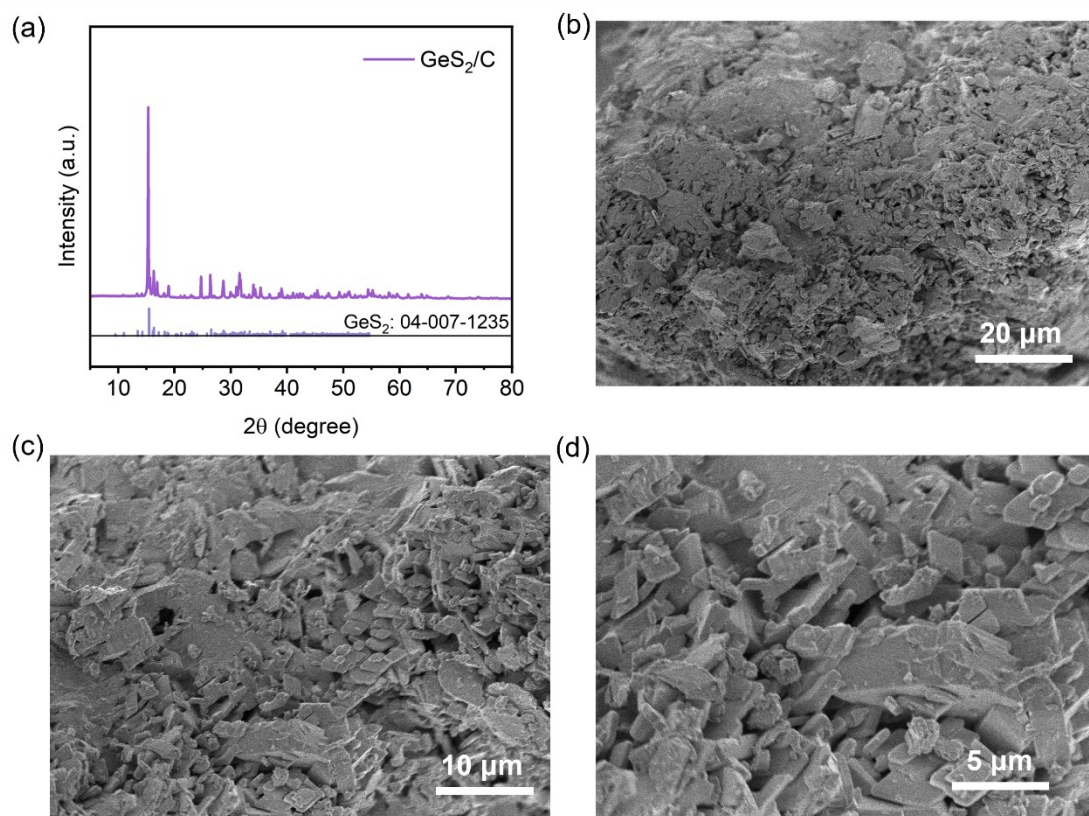


Fig. S3. Physical characterizations of pure GeS_2/C composite. (a) XRD patterns and (b-d) SEM image.

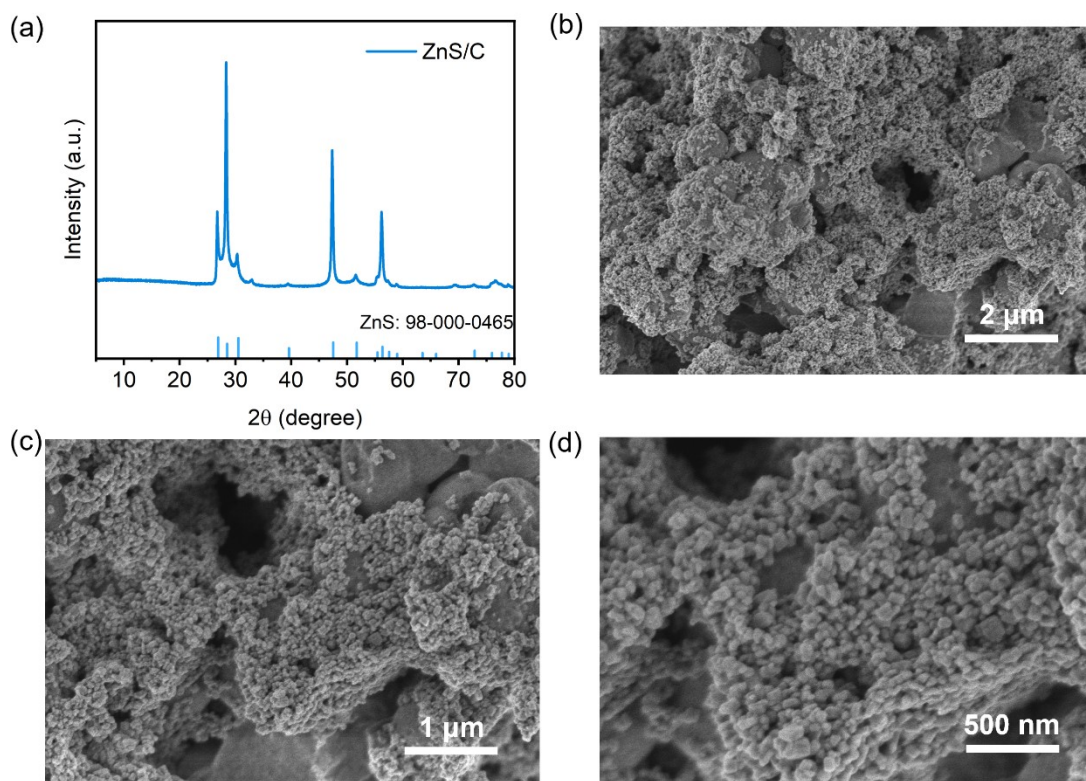


Fig. S4. Physical characterizations of pure ZnS/C composite. (a) XRD patterns and (b-d) SEM image.

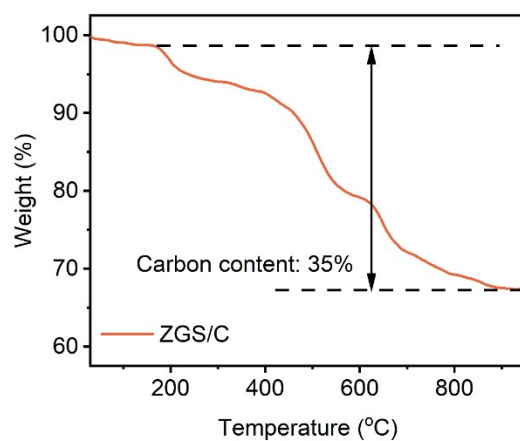


Fig S5. TGA curves of ZGS/C composites.

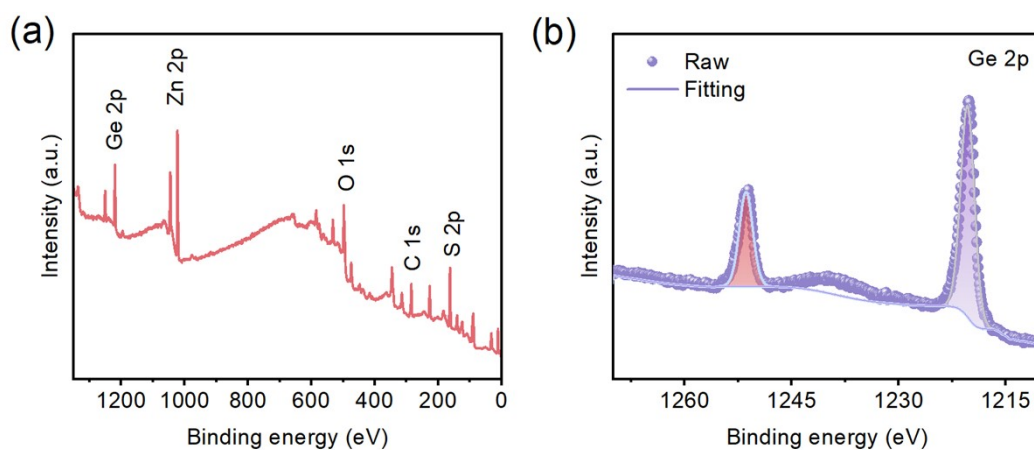


Fig. S6. XPS analysis of ZGS/C composite. (a) Survey spectrum, and (b) Zn 2p high-resolution spectrum.

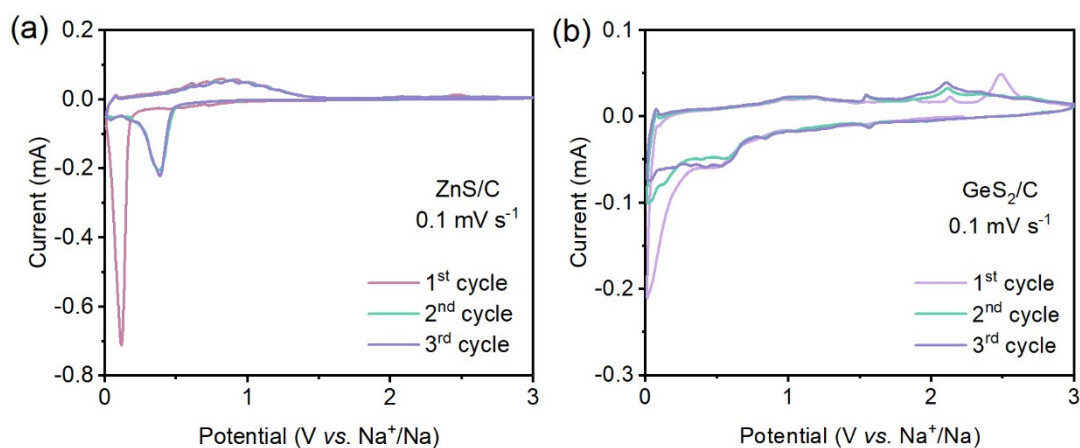


Fig. S7. Initial three CV curves of ZnS/C and GeS₂/C electrodes at 0.1 mV s⁻¹.

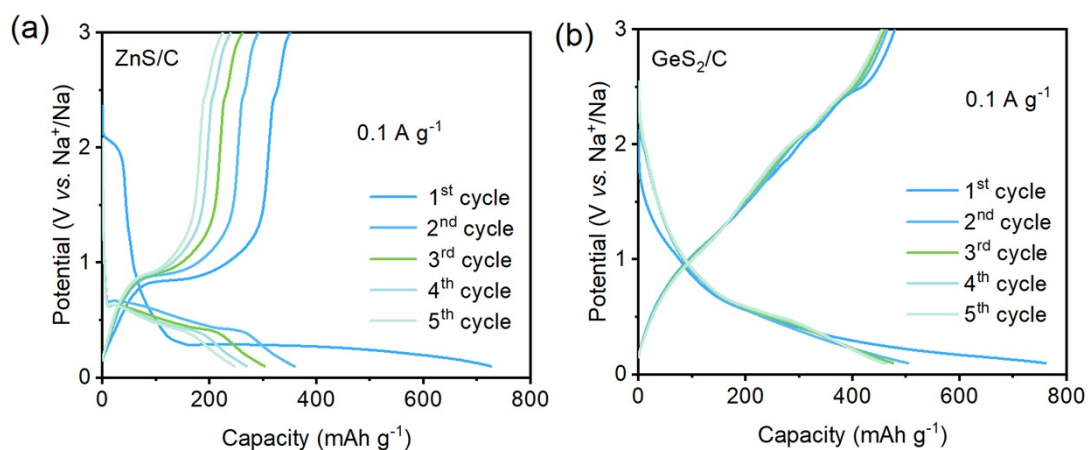


Fig. S8. Initial five discharge-charge curves at 0.1 A g^{-1} , (a) ZnS/C and (b) GeS₂/C electrodes.

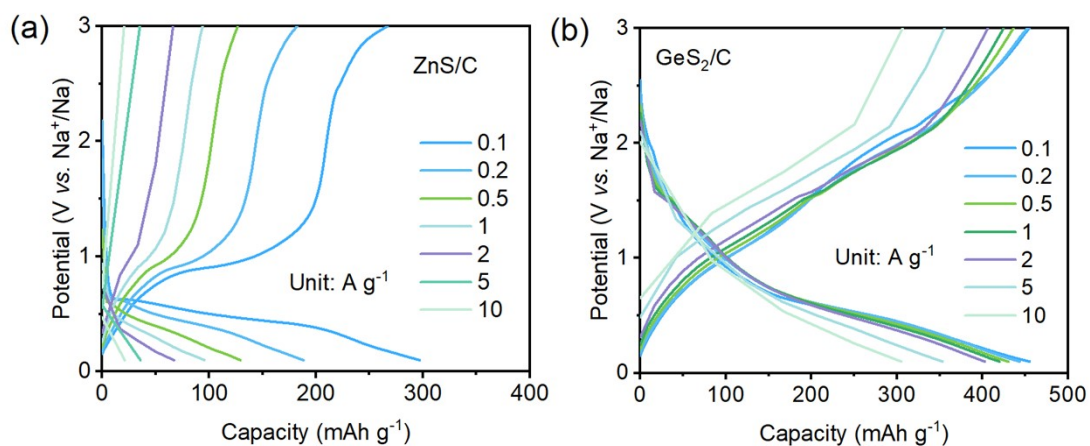


Fig. S9. The discharge-charge curves of (a) ZnS/C and (b) GeS₂/C electrodes at various current rates from 0.1 to 10 A g^{-1} .

Table S1. Comparison of reversible capacity and cycling lifespan with reported ZnS or GeS₂-based anode in SIBs.

Sample	Current (A g ⁻¹)	Capacity (mAh g ⁻¹)	Cycle number (n)	References
NiS/ZnS@C-AT	2	404.5	1900	[1]
ZnS/Co	2	557	1500	[2]
ZnS/NC	1	244.1	900	[3]
N, S-HC@ZnS	2	308.33	1000	[4]
ZnS NSs@rGO	0.5	634.6	1000	[5]
ZSG	1	174.3	1000	[6]
ZnIn ₂ S ₄	5	394.3	500	[7]
2D Ultrathin GeS ₂ Nanosheets	10	515	2000	[8]
GeS ₂ /Graphene	2	371	800	[9]
Carbon confined GeS ₂	0.1	266.5	500	[10]
Amorphous structured GeS ₂	10	512.8	1000	[11]
This work	10	446	3000	

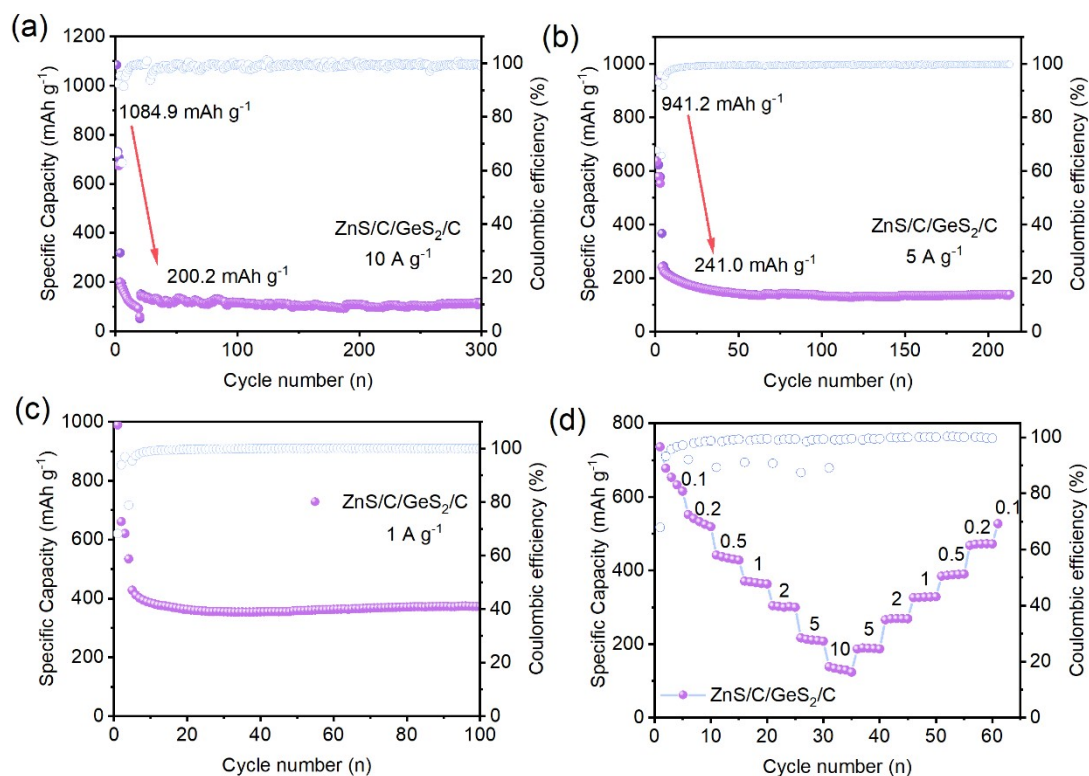


Fig S10. (a-c) Long-term cycling, and (d) rate capability of ZnS/C/GeS₂/C electrode.

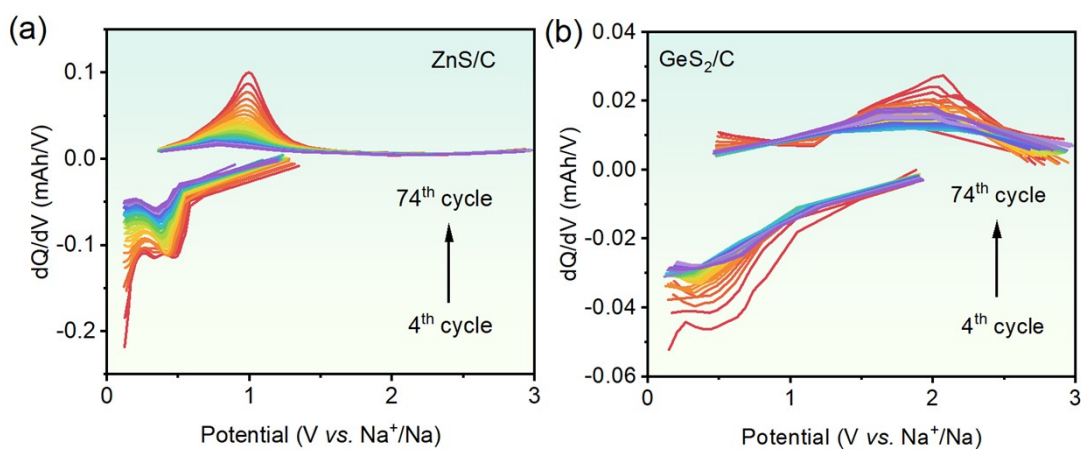


Fig. S11. dQ/dV curves of (a) ZnS/C and (b) GeS₂/C electrodes at 1.0 A g⁻¹.

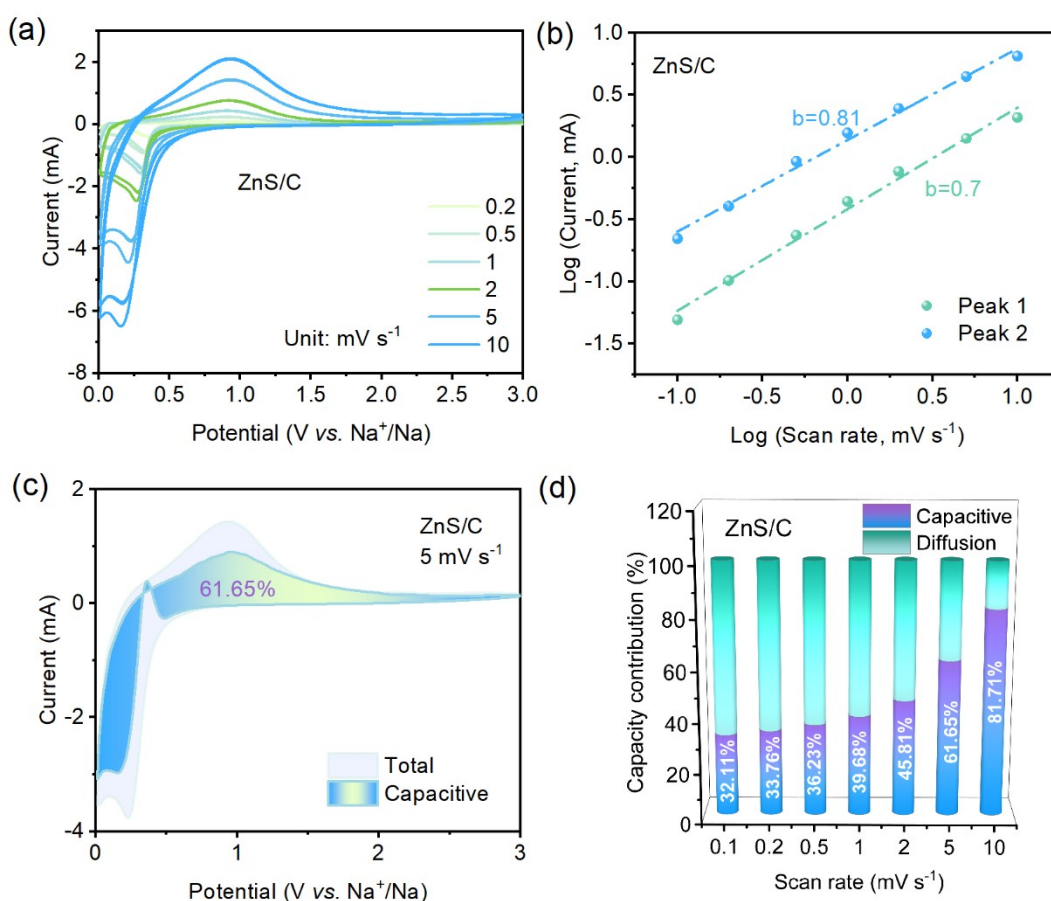


Fig. S12. Reaction kinetics of ZnS/C electrode. (a) Various CV curves at different scan rates from 0.2 to 10 mV s⁻¹. (b) Plot of log (scan rate) vs. log (peak current) from CV curves. (c) Capacitive contribution in the CV curves of ZnS/C electrode at 5 mV s⁻¹. (d) Capacitive contribution of ZnS/C at various scan rates.

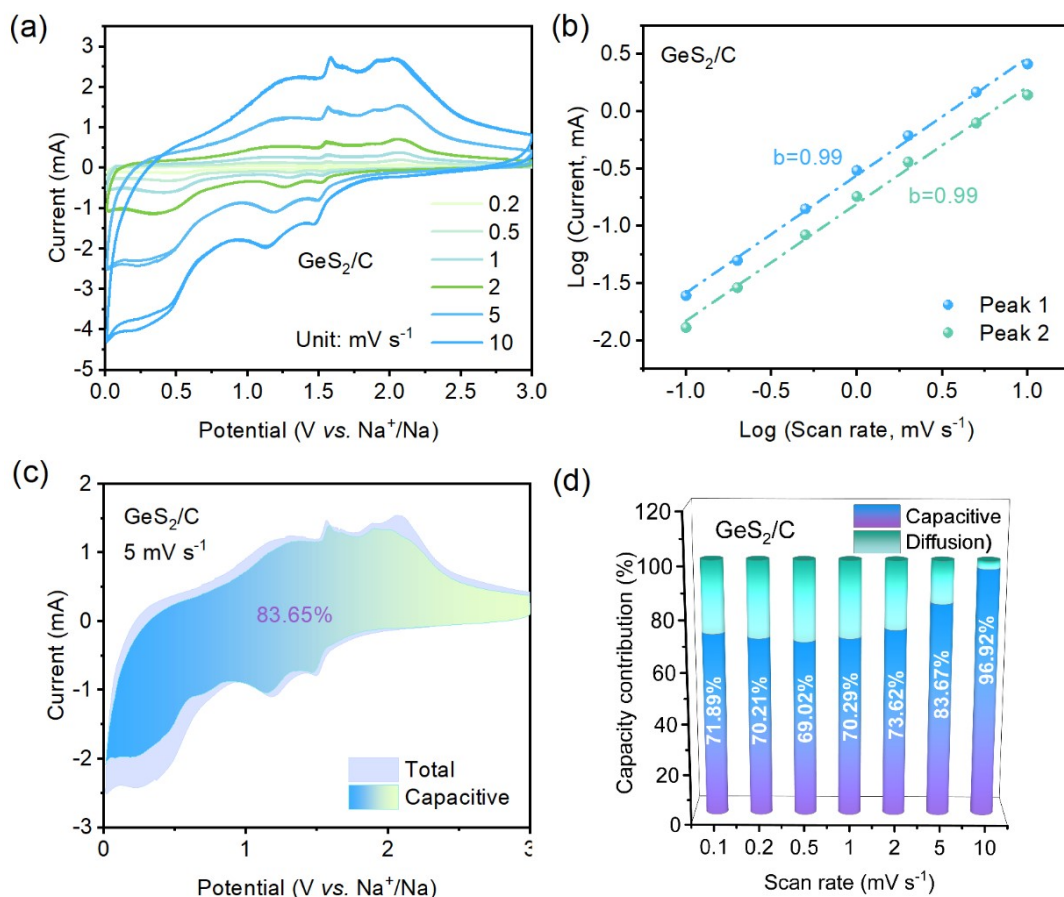


Fig. S13. Reaction kinetics of GeS_2/C electrode. (a) Various CV curves at different scan rates from 0.2 to 10 mV s^{-1} . (b) Plot of $\log(\text{scan rate})$ vs. $\log(\text{peak current})$ from CV curves. (c) Capacitive contribution in the CV curves of GeS_2/C electrode at 5 mV s^{-1} . (d) Capacitive contribution of GeS_2/C at various scan rates.

Table S2. The corresponding data of activation energy in Fig. 4g.

$1000/T$ (K^{-1})	ZGS/C	ZnS/C	GeS_2/C
3.35	-1.73	-2.45	-2.62
3.30	-1.69	-2.49	-2.60
3.25	-1.65	-2.39	-2.59
3.19	-1.56	-2.34	-2.57
3.14	-1.49	-2.18	-1.93

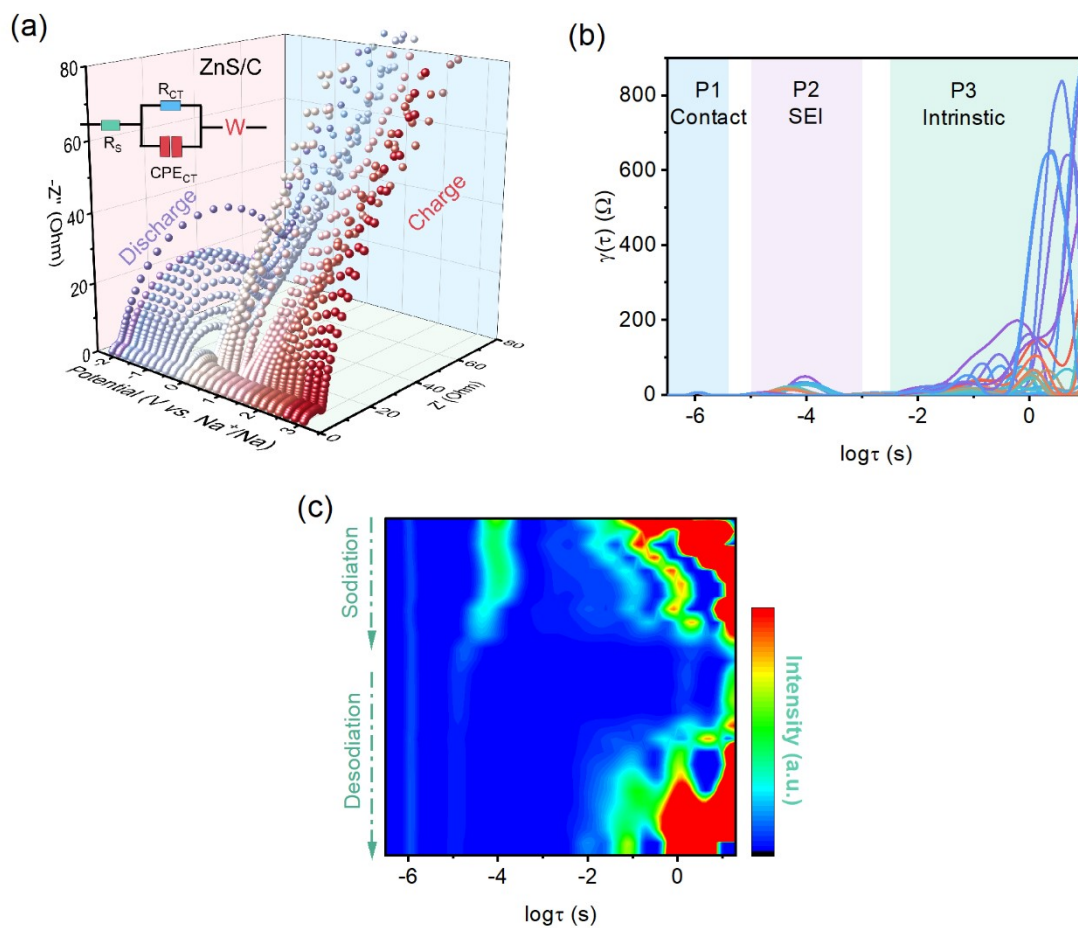


Fig. S14. Characterization of Na⁺ transport in ZnS/C half-cell. (a) In-situ EIS curves. (b) DRT curves and (c) their contour map.

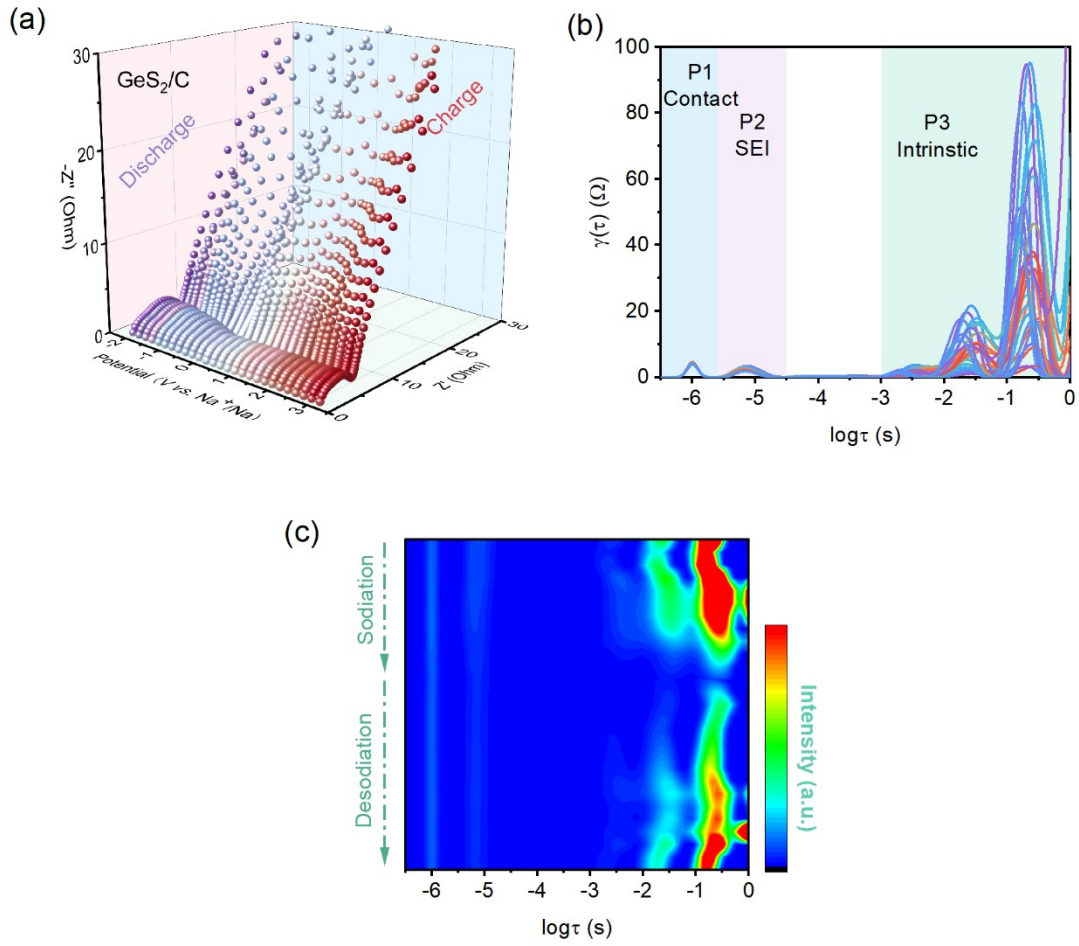


Fig. S15. Characterization of Na⁺ transport in GeS₂/C half-cell. (a) In-situ EIS curves. (b) DRT curves and (c) their contour map.

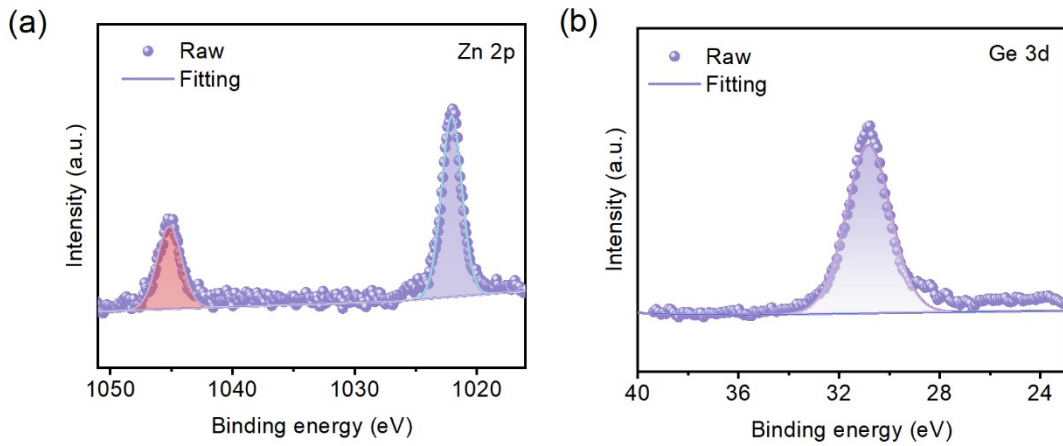


Fig. S16. XPS spectra of ZGS/C electrode after 50 cycles at 1 A g⁻¹: (a) Zn 2p high-resolution spectra and (b) Ge 3d high-resolution spectra.

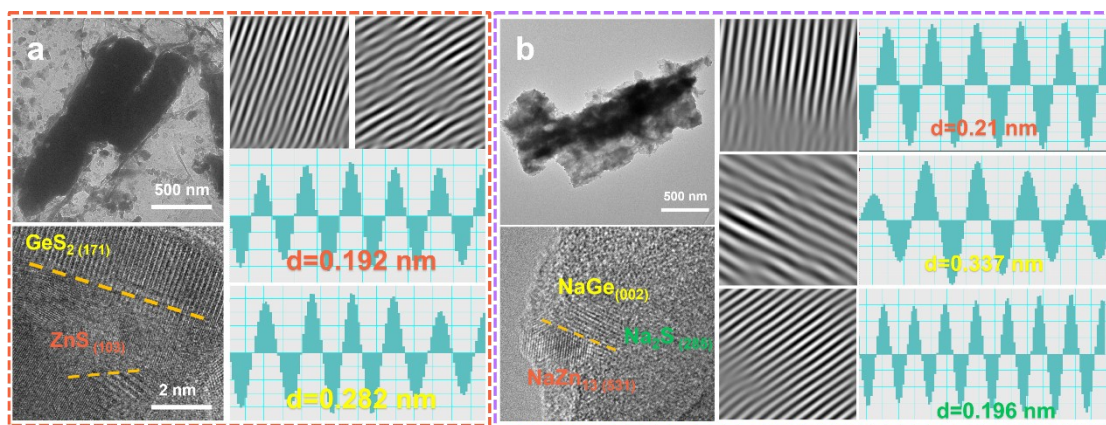


Fig S17. (a, b) HRTEM images of the ZGS/C electrode at the charged state and discharged states.

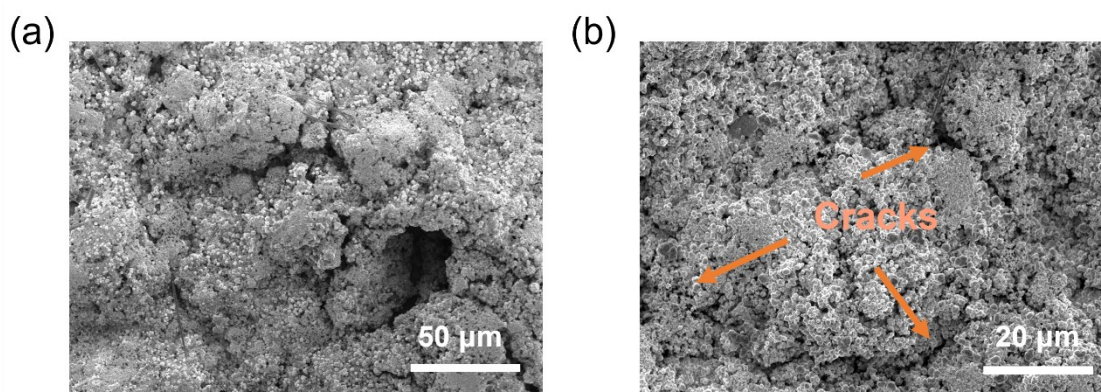


Fig. S18. (a,b) SEM images of ZnS/C electrode after 50 cycles at 1 A g⁻¹.

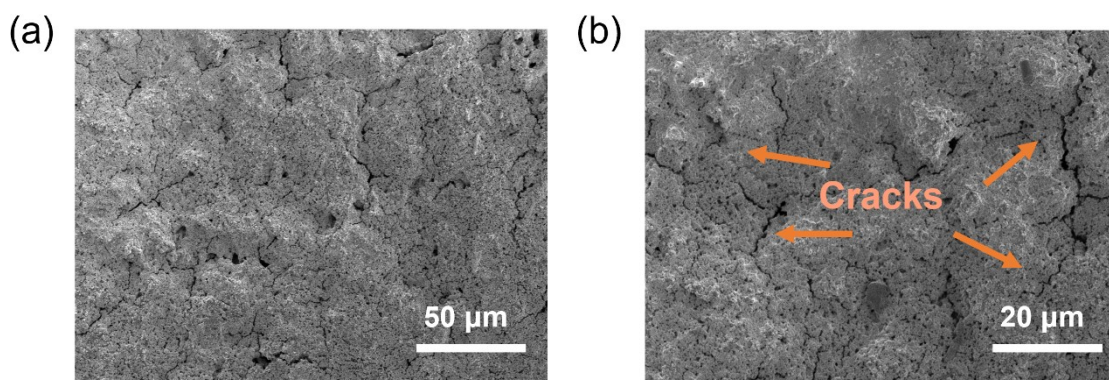


Fig. S19. (a,b) SEM images of GeS₂/C electrode after 50 cycles at 1 A g⁻¹.

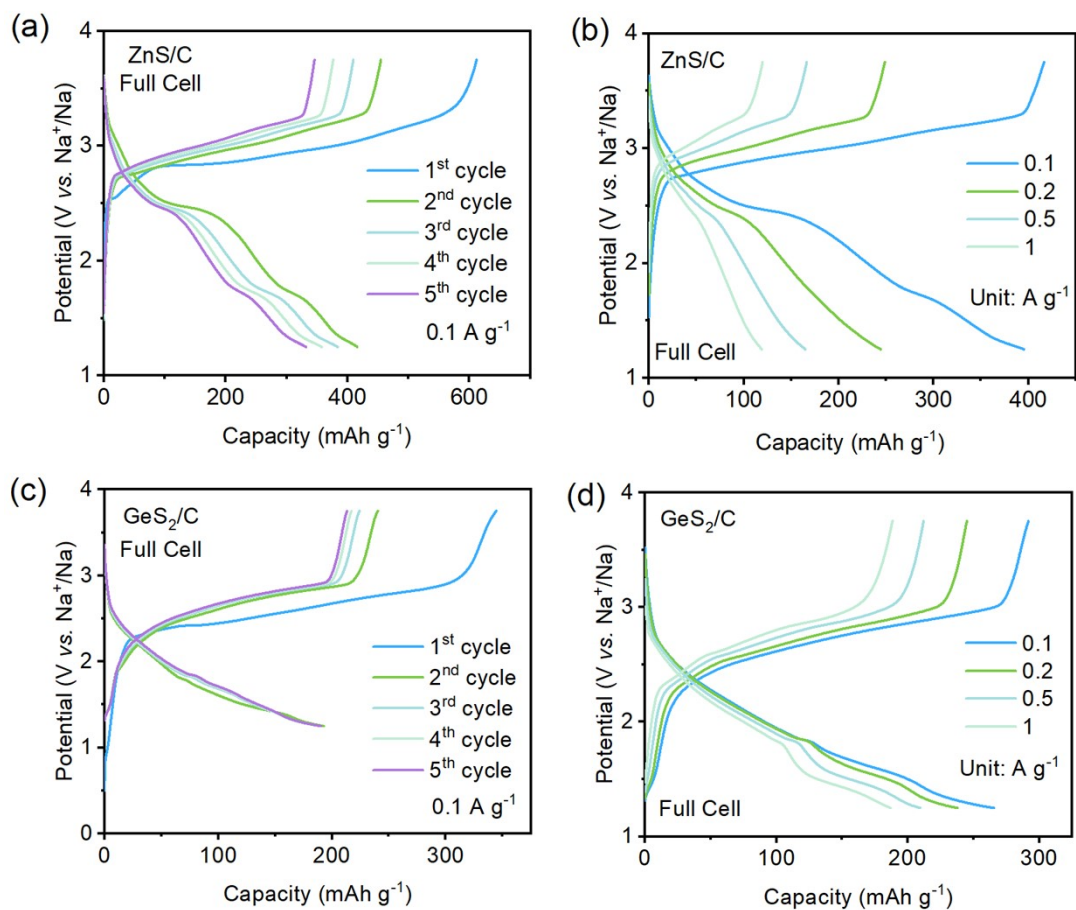


Fig. S20. (a,c) Initial five discharge-charge curves of ZnS/C and GeS₂/C electrodes at 0.1 A g⁻¹. (b,d) The discharge-charge curves at various current rates from 0.1 to 1 A g⁻¹ of ZnS/C and GeS₂/C electrodes.

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